

Opportunities for Two-color Experiments at the SASE3 undulator line of the European XFEL



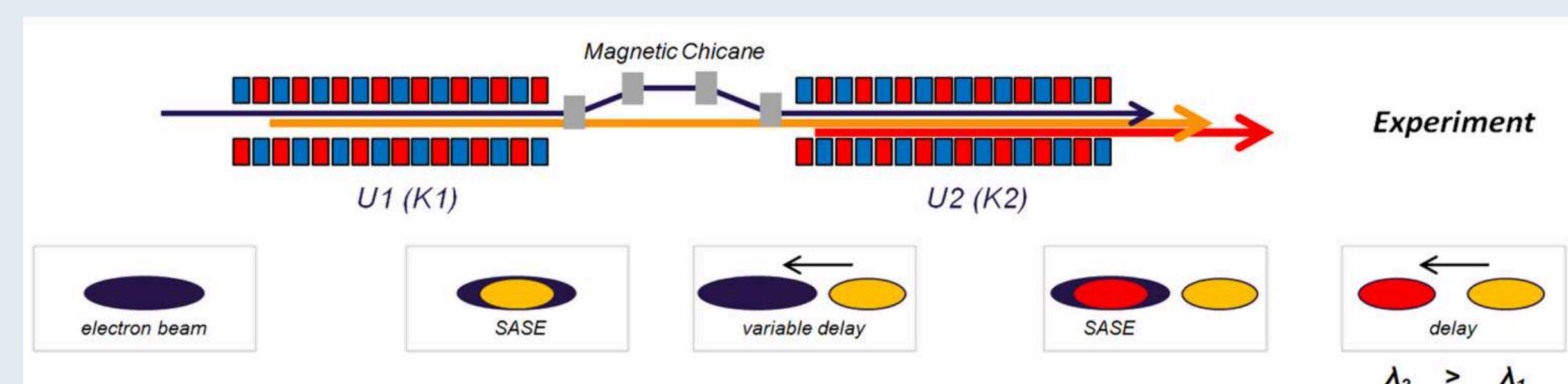
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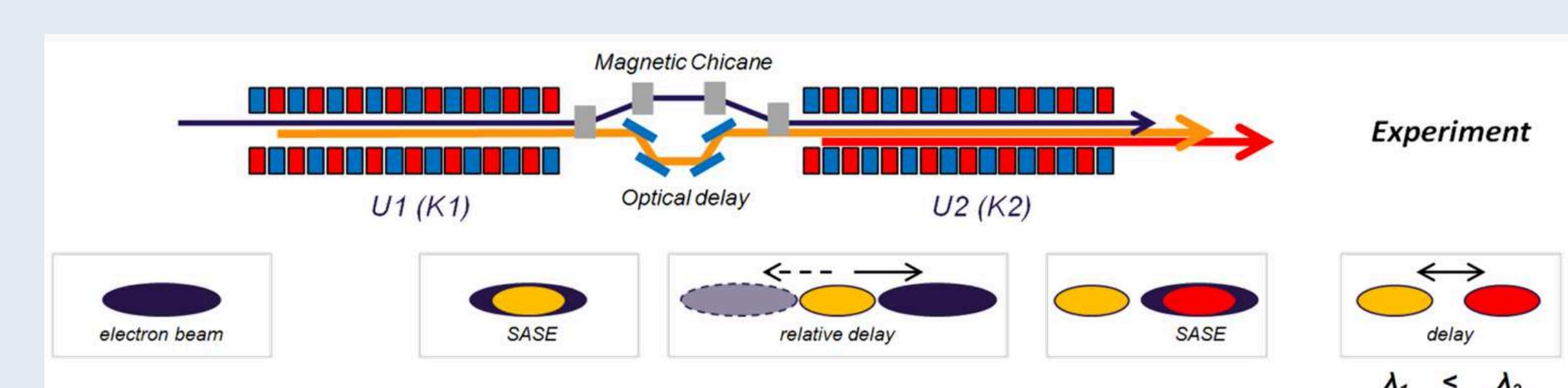
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Method

- Aiming at X-ray-pump/X-ray-probe in the Soft X-ray region
- Simplest, cost-effective way for generating two-colors



- Inserting an optical delay allows for scanning through zero delay

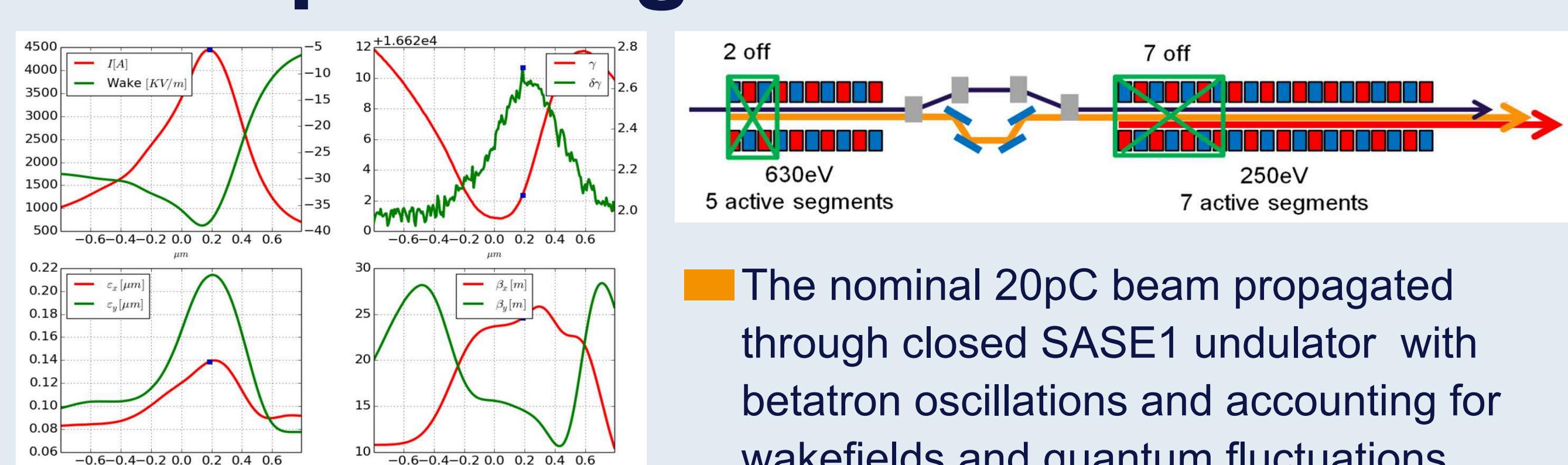


- Funded and to be installed at SASE3
- Expected tuneability between 250eV and 3000eV
- Expected max delay: several hundreds of femtoseconds

SQS science case

- Site-specific pump and probe
- Example: charge transfer in a linear molecule ($\text{I}-\text{C}_n-\text{H}_{2n}-\text{Cl}$)
- Cl 2p electron threshold at 210eV
- I 3d electron threshold at 630eV
- Intramolecular process investigation via:
 - High-resolution Auger spectroscopy
 - Ion spectroscopy
 - Electron-ion coincidence
- Coincidence arrangement feasible due to the high-rep rate of the European XFEL
- Possible experiment:
 - Individual Auger spectra at 250eV and 630eV; coincidence provides charge and fragment resolved spectra
 - Delay scan of 250eV-pulse vs. the 630eV-pulse
- Short pulses are needed → low electron beam charge

Setup settings



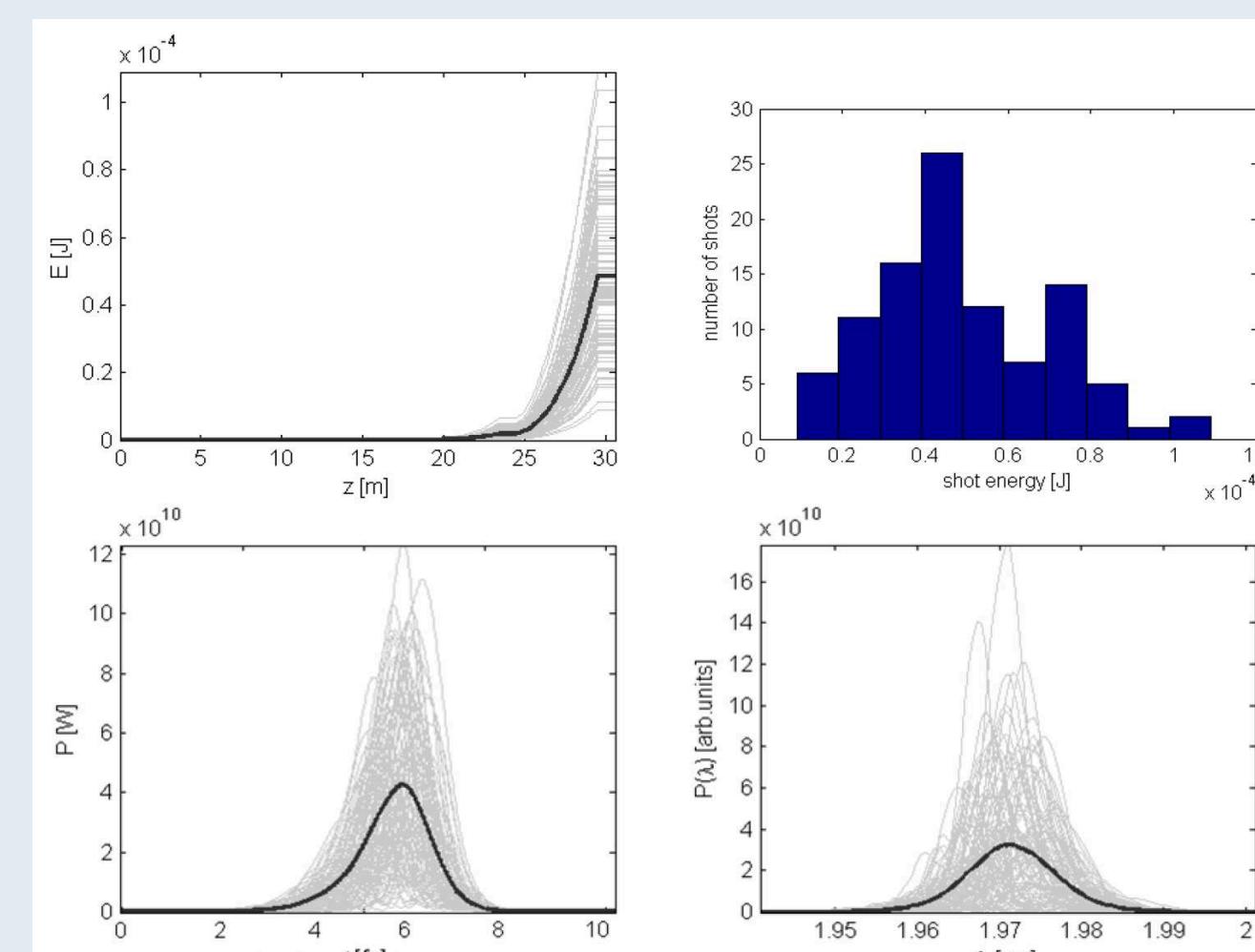
- The nominal 20pC beam propagated through closed SASE1 undulator with betatron oscillations and accounting for wakefields and quantum fluctuations

FEL Simulations

- Performed with GENESIS simulation code

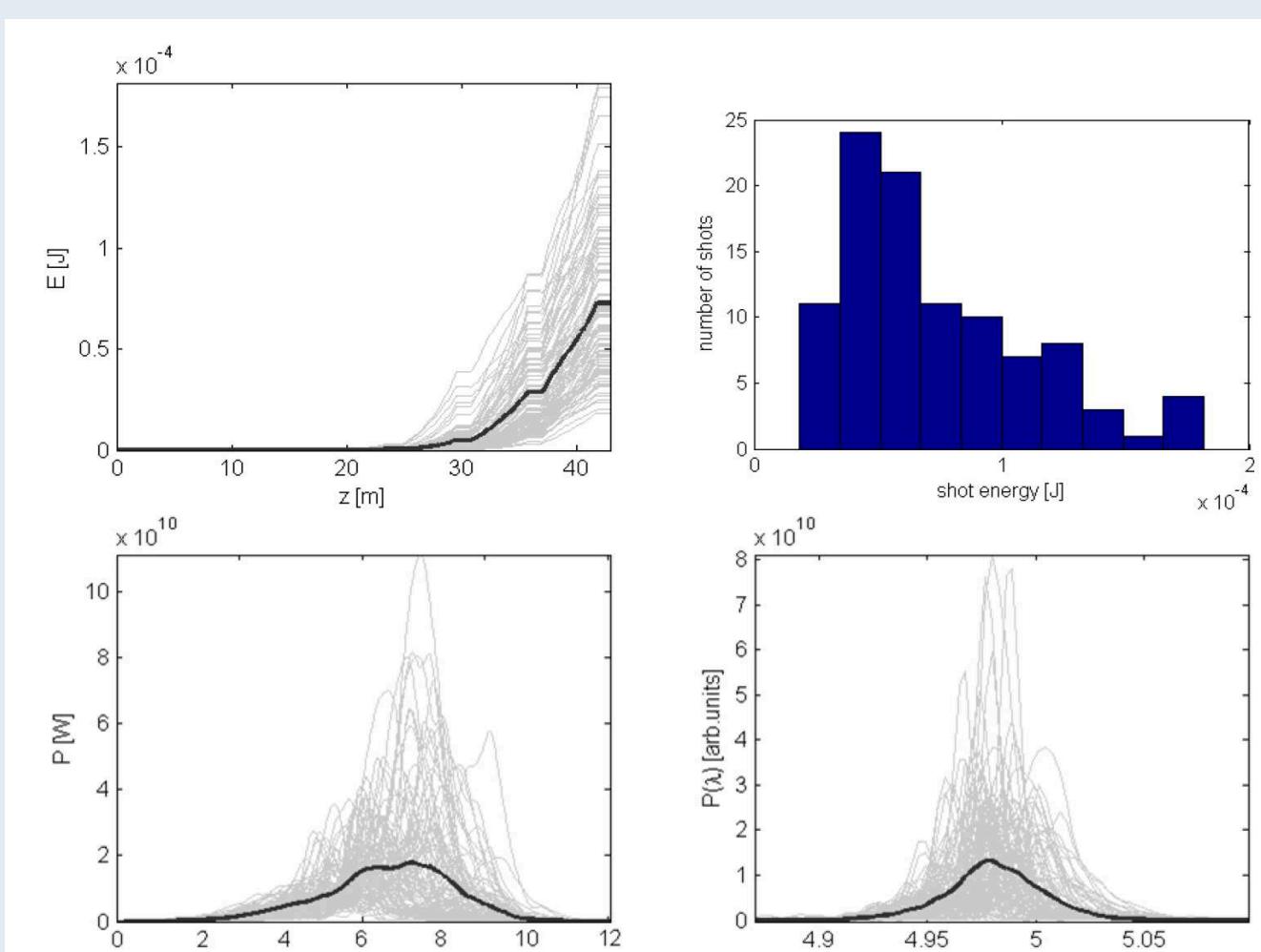
Radiation after **U1 @ 630 eV:**

Mean energy per pulse is 50 μJ,
(5×10^{11} photons/pulse avg.)



Radiation after **U2 @ 250 eV:**

Mean energy per pulse is 70 μJ,
(1.7×10^{12} photons/pulse avg.)



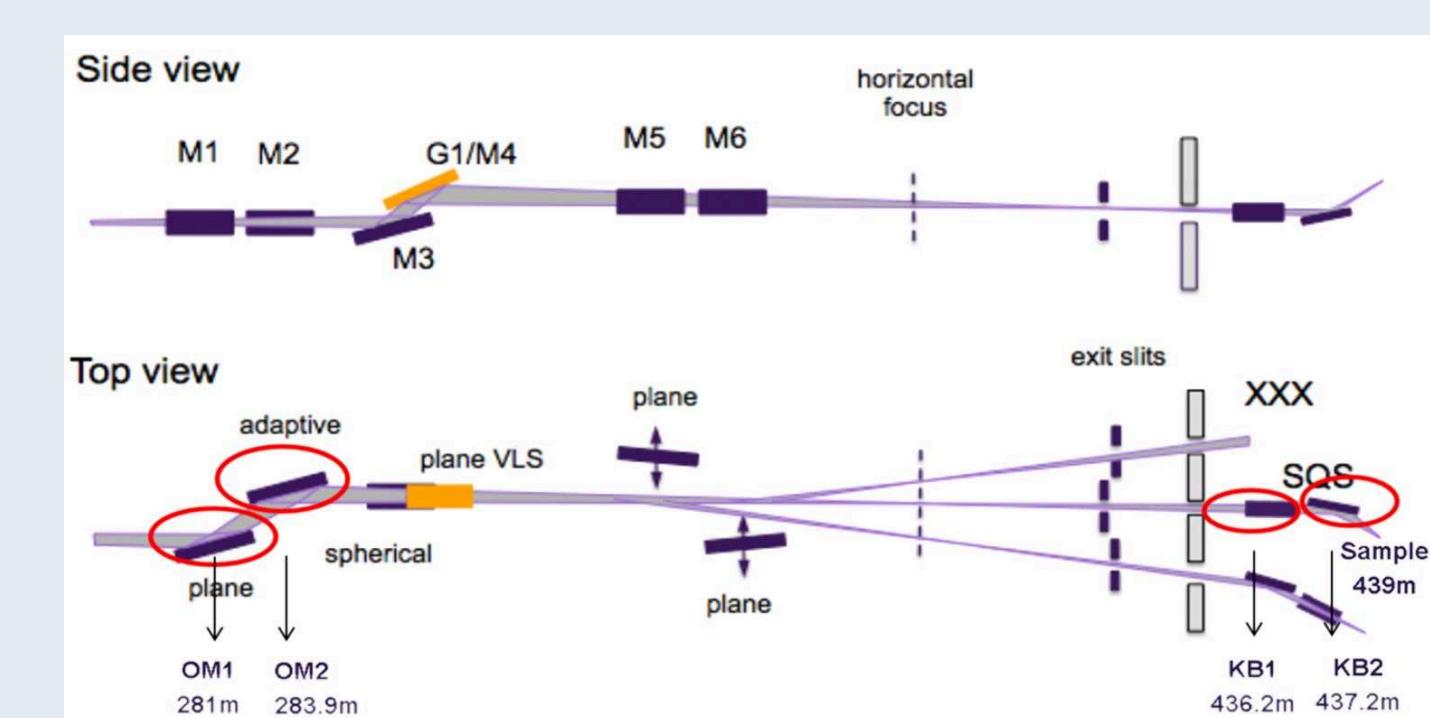
- Top left: pulse energy growth along the undulator
- Top right: distribution of FEL shots with different energies per pulse
- Bottom left: power along the FEL pulses
- Bottom right: corresponding spectra.

Wavefront propagation

- Performed with SRW simulation code

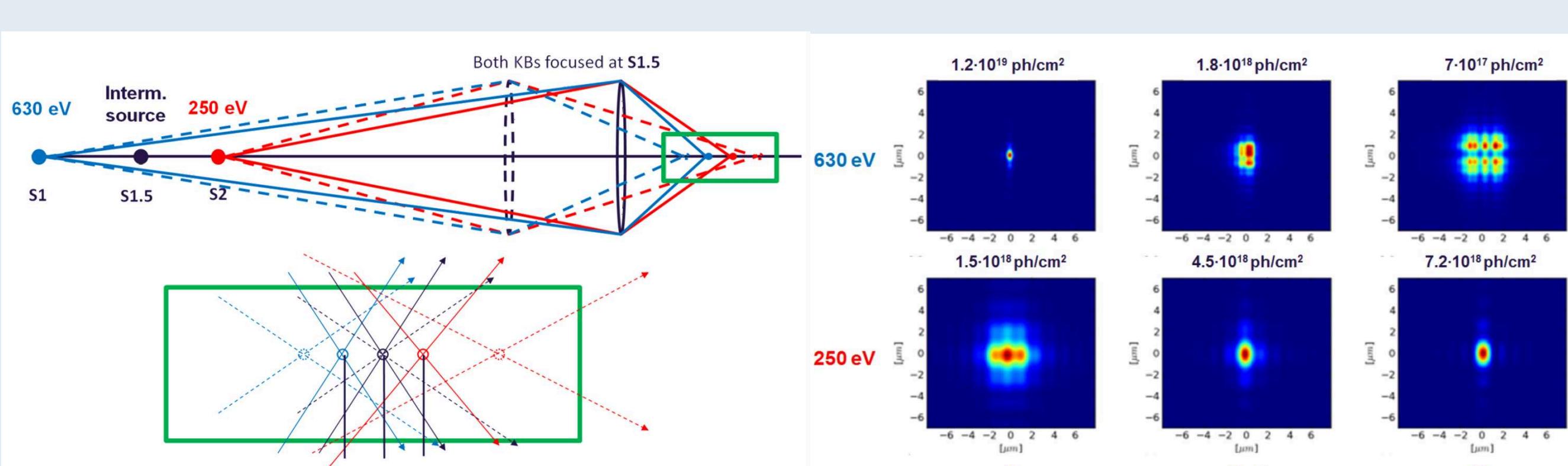
■ Optical elements considered:
offset mirrors and KB mirrors
(grazing incidence of 9mrad is assumed for all)

■ Accounted for: reflectivity of B4C on Si substrate, mirror height errors, diffraction on edges.



Focusing on the sample

- In a single optical system, two distinct sources (S1 and S2) imply two distinct images (I1 and I2)



- Reimaging artificial intermediate source S1.5 onto the sample, assumed at I1.5 allows to minimize aberrations and obtain comparable radiation size and photon flux density (reaching beyond 10^{18} photons/cm² per pulse).